

View Online at <https://aerobasegroup.com/nsn/5961-01-081-0332>

**Inclosure Material:**

Glass and plastic

**Overall Length:**

0.275 inches

**Overall Height:**

0.070 inches

**Overall Width:**

0.260 inches

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-86

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Press fit

**Features Provided:**

Hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

80.0 collector to base voltage, dc all transistor and 80.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor

**Current Rating Per Characteristic:**

600.00 milliamperes source cutoff current all transistor

**Power Rating Per Characteristic:**

500.0 milliwatts small-signal input power, common-collector absolute all transistor

**Maximum Operating Temperature Per Measurement Point:**

200.0 degrees celsius junction

**Special Features:**

All transistor junction pattern arrangement: npn

**Terminal Type And Quantity:**

14 ribbon

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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